



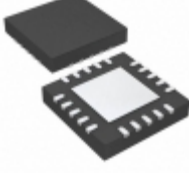


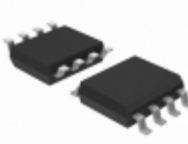
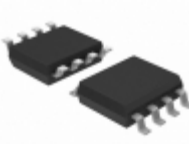
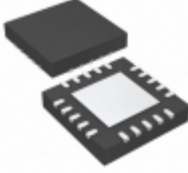
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|-----------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|  | <p>SI4362BDY-T1-E3</p> |
| | <p>Hersteller-Teilenummer: SI4362BDY-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 29A 8-SOIC</p> <p>Datenblätter:  SI4362BDY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 99280 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--------------------------------------------------|-----------------------------------------------------------------------------------|
| Teilenummer | SI4362BDY-T1-E3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N-CH 30V 29A 8-SOIC |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | 99280 pcs Stock |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | 8-SOIC (0.154", 3.90mm Width) |
| Supplier Device-Gehäuse | 8-SO |
| Verlustleistung (max) | 3W (Ta), 6.6W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 29A (Tc) |
| Rds On (Max) @ Id, Vgs | 4.6 mOhm @ 19.8A, 10V |
| VGS (th) (Max) @ Id | 2V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 115nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 4800pF @ 15V |
| Verpackung | Tape & Reel (TR) |



















































SI4362BDY-T1-E3 ist neu im Original, Suche SI4362BDY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4362BDY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4362BDY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|  <p>SI4362BDY-T1 VISHAY VISHAY SOP8</p> |  <p>SI4362DT-T1-E3 VISHAY SI4362DT-T1-E3 VISHAY</p> |  <p>SI4362-C2A-GMR Energy Micro (Silicon Labs) IC RCVR EZRADIO SUB GHZ 20QFN</p> |  <p>SI4362-B1B-FMR Energy Micro (Silicon Labs) IC EZRADIO PRO RX 20QFN</p> |
|  <p>SI4362BDY-T1-E3-PBF VISHAY SI4362BDY-T1-E3-PBF VISHAY</p> |  <p>SI4362BDY-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 29A 8-SOIC</p> |  <p>SI4362BDY-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 29A 8-SOIC</p> |  <p>SI4362-C2A-GM Energy Micro (Silicon Labs) EZRADIOPRO SUB GHZ RECEIVER, -11</p> |

heiße Teile

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|  SI4340CDY-T1-E3 |  SI4340CDY-T1-E3 |  SI4340CDY-T1-E3-S |  SI4340DY |  SI4340DY-T1 |
|  SI4340DY-T1-E3 |  SI4340DY-T1-E3 |  SI4346DY |  SI4346DY-T1-E3 |  SI4346DY-T1-E3 |
|  SI4346DY-T1-GE3 |  SI4346DY-T1-GE3 |  SI4348DY |  SI4348DY-T1-E3 |  SI4348DY-T1-E3 |
|  SI4348DY-T1-GE3 |  SI4354DY-T1-E3 |  SI4354DY-T1-E3 |  SI4355-B1A-FMR |  SI4356ADY-T1-E3 |
|  SI4356DY |  SI4356DY-T1 |  SI4356DY-T1-E3 |  SI4362BDY |  SI4362BDY-T1-E3 |
|  SI4362BDY-T1-E3-PBF |  SI4362DY |  SI4362DY-T1 |  SI4362DY-T1-E3 |  SI4362DY-T1-E3. |
|  SI4364DY |  SI4364DY-T1 |  SI4364DY-T1-E3 |  SI4366DY-T1-E3 |  SI4368DY |
|  SI4368DY-T1-E3 |  SI4368DY-T1-E3 |  SI4370DY-T1-E3 |  SI4376DY-T1-E3 |  SI4378DY-T1 |
|  SI4378DY-T1-E3 |  SI4378DY-T1-E3 |  SI4382DY-T1-E3 |  SI4384DY |  SI4384DY-T1-E3 |
|  SI4384DY-T1-E3 |  SI4384DY-T1-E3.. |  SI4386DY |  SI4386DY-T1-E3 |  SI4386DY-T1-E3 |

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